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Vacuum, Surfaces, and Films

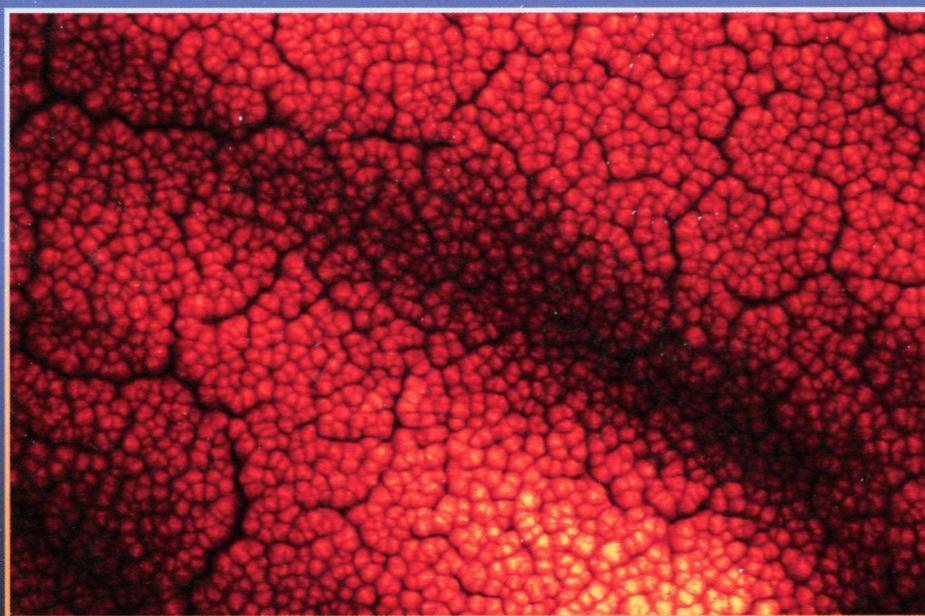


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Review Articles:

Nonisostructural Complex Oxide Heteroepitaxy

-by Franklin J. Wong and Shriram Ramanathan

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On The Cover: Phillip D. Swartzentruber, Thomas John Balk, and Michael P. Effgen, *JVST A* 32(4), p. 040601-1 (2014). Cover shows the nanocrystalline grain structure of an as-deposited osmium-ruthenium alloy thin film. The film enhances thermionic emission from dispenser cathodes.